

PROTECTION PRODUCTS - RailClamp[®] Description

RailClamps are surge rated diode arrays designed to protect high speed data interfaces. The SRDA series has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by electrostatic discharge (ESD), electrical fast transients (EFT), and lightning.

The unique design incorporates surge rated, low capacitance steering diodes and a TVS diode in a single package. During transient conditions, the steering diodes direct the transient current to ground via the internal low voltage TVS. The TVS diode clamps the transient voltage to a safe level. The low capacitance array configuration allows the user to protect up to four high-speed data lines.

The SRDA3.3-4 is constructed using Semtech's proprietary EPD process technology. The EPD process provides low stand-off voltages with significant reductions in leakage current and capacitance over silicon-avalanche diode processes. They feature a true operating voltage of 3.3 volts for superior protection.

These devices are in a 8-pin SOIC package. It measures 3.9×4.9 mm. They are available with a SnPb or RoHS/WEEE compliant matter tin lead finish. The high surge capability (Ipp=25A, tp=8/20µs) means it can be used in high threat environments in applications such as CO/CPE equipment, telecommunication lines, and video lines.

Features

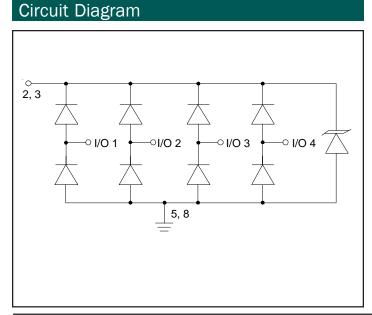
- ◆ Transient protection for high-speed data lines to IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact) IEC 61000-4-4 (EFT) 40A (5/50ns) IEC 61000-4-5 (Lightning) 24A (8/20µs)
- ◆ Array of surge rated diodes with internal TVS diode
- Protects four I/O lines
- ◆ Low capacitance (<15pF) for high-speed interfaces
- Low operating voltage: 3.3V
- Low clamping voltage
- Solid-state technology

Mechanical Characteristics

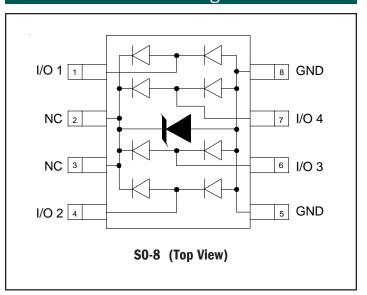
- JEDEC SOIC-8 package
- Lead Finish: SnPb or Matte Sn
- Molding compound flammability rating: UL 94V-0
- Marking : Part number, date code, logo
- Packaging : Tape and Reel per EIA 481

Applications

- T1/E1 secondary IC Side Protection
- ◆ T3/E3 secondary IC Side Protection
- Analog Video Protection
- Microcontroller Input Protection
- Base stations
- I²C Bus Protection



Schematic and PIN Configuration



SEMTECH

PROTECTION PRODUCTS

Absolute Maximum Rating

Rating	Symbol	Value	Units
Peak Pulse Power ($t_p = 8/20\mu s$)	P _{pk}	500	Watts
Peak Pulse Current (t _p = 8/20µs)	۱ _{pp}	25	A
Lead Soldering Temperature	TL	260 (10 sec.)	°C
Operating Temperature	T,	-40 to +85	°C
Storage Temperature	Т _{sтg}	-55 to +150	°C

Electrical Characteristics (T=25°C)

SRDA3.3-4										
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units				
Reverse Stand-Off Voltage	V _{RWM}				3.3	V				
Punch-Through Voltage	V _{PT}	Ι _{ΡΤ} = 2μΑ	3.5			V				
Snap-Back Voltage	V _{SB}	I _{sb} = 50mA	2.8			V				
Reverse Leakage Current	I _R	V _{RWM} = 3.3V, T=25°C			1	μA				
Clamping Voltage	V _c	I _{pp} = 1A, t _p = 8/20μs			5.3	V				
Clamping Voltage	V _c	I _{pp} = 10A, t _p = 8/20µs			10	V				
Clamping Voltage	V _c	I _{pp} = 25Α, t _p = 8/20μs			15	V				
Junction Capacitance	C _j	Between I/O pins and Ground V _R = OV, f = 1MHz		8	15	pF				
		Between I/O pins V _R = OV, f = 1MHz		4		pF				

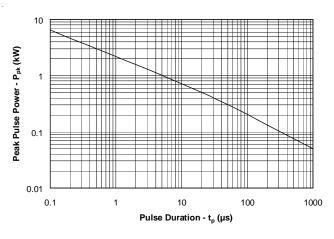
SRDA3.3-4



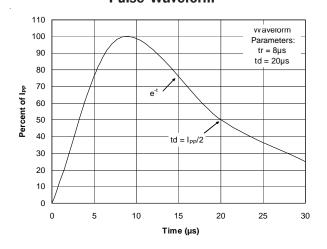
PROTECTION PRODUCTS

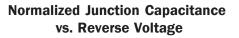
Typical Characteristics

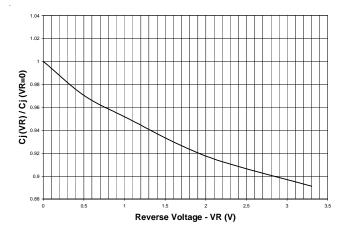
Non-Repetitive Peak Pulse Power vs. Pulse Time



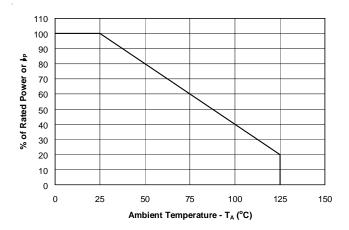
Pulse Waveform



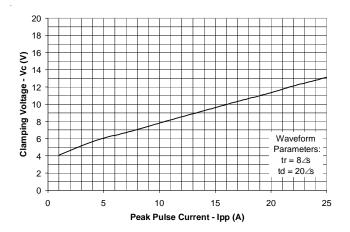




Power Derating Curve



Clamping Voltage vs. Peak Pulse Current





Applications Information

Device Connection Options for Protection of Four High-Speed Data Lines

These devices are designed to protect low voltage data lines operating at 3.3 volts. When the voltage on the protected line exceeds the punch-through or "turn-on" voltage of the TVS diode, the steering diodes are forward biased, conducting the transient current away from the sensitive circuitry.

Data lines are connected at pins 1, 4, 6 and 7. Pins 5 and 8 should be connected directly to a ground plane. The path length is kept as short as possible to minimize parasitic inductance.

Note that pins 2 and 3 are connected internally to the cathode of the low voltage TVS. It is not recommended that these pins be directly connected to a DC source greater than the snap-back vollage (V_{SB}) as the device can latch on as described below.

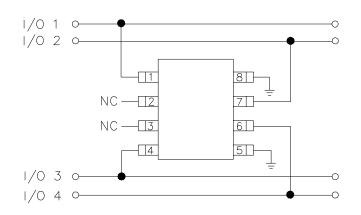
EPD TVS Characteristics

These devices are constructed using Semtech's proprietary EPD technology. By utilizing the EPD technology, the SRDA3.3-4 can effectively operate at 3.3V while maintaining excellent electrical characteristics.

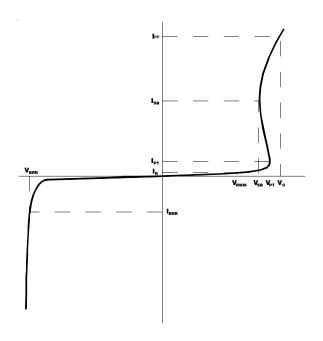
The EPD TVS employs a complex nppn structure in contrast to the pn structure normally found in traditional silicon-avalanche TVS diodes. Since the EPD TVS devices use a 4-layer structure, they exhibit a slightly different IV characteristic curve when compared to conventional devices. During normal operation, the device represents a high-impedance to the circuit up to the device working voltage (V_{RWM}). During an ESD event, the device will begin to conduct and will enter a low impedance state when the punch through voltage (V_{PT}) is exceeded. Unlike a conventional device, the low voltage TVS will exhibit a slight negative resistance characteristic as it conducts current. This characteristic aids in lowering the clamping voltage of the device, but must be considered in applications where DC voltages are present.

When the TVS is conducting current, it will exhibit a slight "snap-back" or negative resistance characteristics due to its structure. This point is defined on the curve by the snap-back voltage (V_{sr}) and snap-back

Data Line Protection Using Internal TVS Diode as Reference





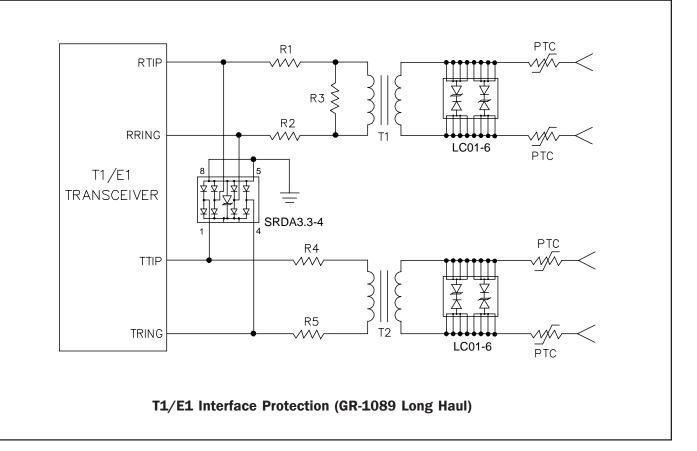


current (I_{SB}). To return to a non-conducting state, the current through the device must fall below the I_{SB} (approximately <50mA) and the voltage must fall below the V_{SB} (normally 2.8 volts for a 3.3V device). If a 3.3V TVS is connected to 3.3V DC source, it will never fall below the snap-back voltage of 2.8V and will therefore stay in a conducting state.



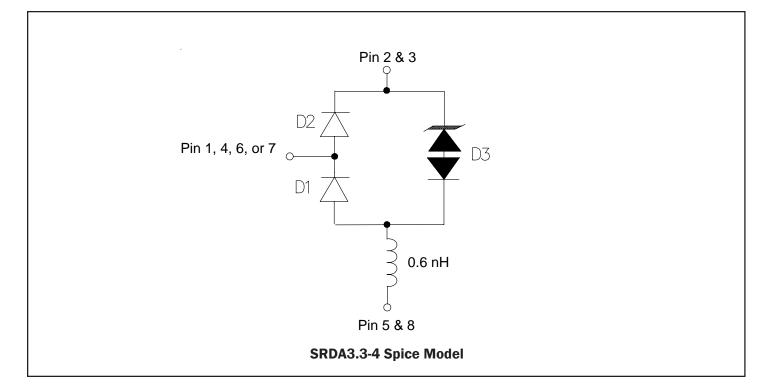


Typical Applications





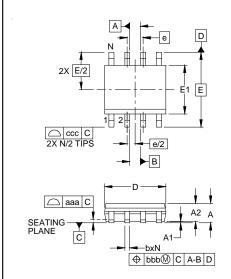
Applications Information - Spice Model

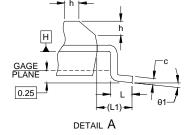


SRDA3.3-4 Spice Parameters								
Parameter	Unit	D1 (LCRD)	D1 (LCRD) D2 (LCRD)					
IS	Amp	2.092E-11	2.156E-12	6.09E-14				
BV	Volt	680	240	3.54				
VJ	Volt	0.62	0.64	13.8				
RS	Ohm	0.180	0.155	0.220				
IBV	Amp	1E-3	1E-3	10E-3				
CJO	Farad	5.2E-12	6.2E-12	45E-12				
TT	sec	2.541E-9	2.541E-9	2.541E-9				
М		0.058	0.058	0.111				
N		1.1	1.1	1.1				
EG	eV	1.11	1.11	1.11				



Outline Drawing - SO-8





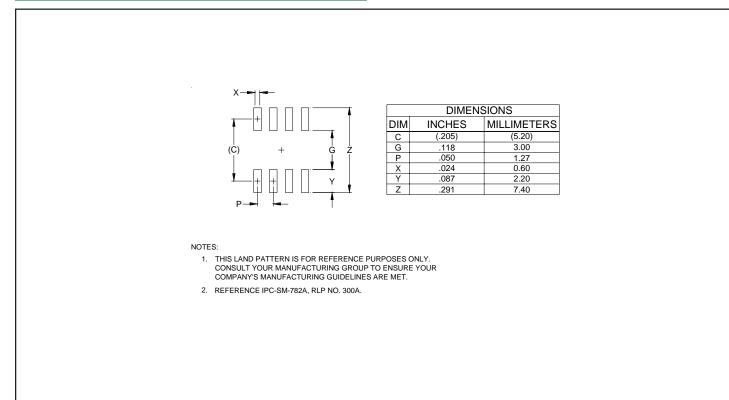


DIMENSIONS								
DIM	11	NCHE	S	MILLIMETERS				
	MIN	NOM	MAX	MIN	NOM	MAX		
Α	.053	-	.069	1.35	-	1.75		
A1	.004	-	.010	0.10	-	0.25		
A2	.049	-	.065	1.25	-	1.65		
b	.012 -		.020	0.31	-	0.51		
С	.007	-	.010	0.17	-	0.25		
D	.189 .193		.197	4.80	4.90	5.00		
E1	.150 .154		.157	3.80	3.90	4.00		
E	.2	236 BS	С	6	.00 BS	С		
е	.(050 BS	С	1.27 BSC				
h	.010	-	.020	0.25	-	0.50		
L	.016	.028	.041	0.40 0.72		1.04		
L1		(.041)		(1.04)				
N	8			8				
θ1	0° -		8°	0° -		8°		
aaa	.004			0.10				
bbb	.010			0.25				
CCC	.008			0.20				

NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. DATUMS -A- AND -B- TO BE DETERMINED AT DATUM PLANE -H-
- DIMENSIONS "E1" AND "D" DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.
- 4. REFERENCE JEDEC STD MS-012, VARIATION AA.

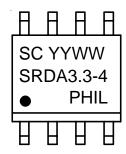
Land Pattern - SO-8



SRDA3.3-4



Marking Diagram



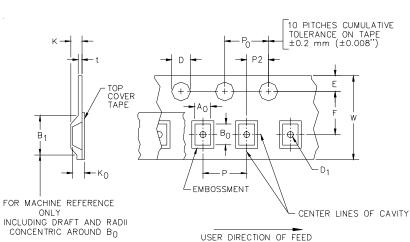
Ordering Information

Part Number	Number Lead Finish Qty per Reel		Reel Size	
SRDA3.3-4.TB	SnPb	500	7 Inch	
SRDA3.3-4.TBT	Matte Sn	500	7 Inch	

Note: Lead-free devices are RoHS/WEEE Compliant

Note: YYWW = Date Code

Tape and Reel Specification



Pin 1 Location

User Direction of feed

Device Orientation in Tape

AO	В0	ко		
6.50 +/-0.20 mm	5.40 +/-0.20 mm	2.00 +/-0.10 mm		

Tape Width	B, (Max)	D	D1	E	F	K (MAX)	Ρ	PO	P2	T(MAX)	w
12 mm	8.2 mm	1.5 + 0.1 mm - 0.0 mm	1.5 mm	1.750±.10 mm	5.5±0.05 mm	4.5 mm	4.0±0.1 mm	4.0±0.1 mm	2.0±0.05 mm	0.4 mm	12.0 mm ±0.3

Contact Information

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